



Docket No.: R2184.0282/P282  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

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In re Patent Application of:  
Hirokazu Iwata et al.

Application No.: 10/765,502

Confirmation No.: 2556

Filed: January 28, 2004

Art Unit: 1722

For: METHODS OF GROWING A GROUP III  
NITRIDE CRYSTAL (AS AMENDED)

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Examiner: R. Kunemund

**AMENDMENT IN RESPONSE TO NON-FINAL OFFICE ACTION**

MS Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action dated August 22, 2006, please amend the above-identified U.S. patent application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 3 of this paper.

**Remarks/Arguments** begin on page 13 of this paper.